

1. Description

UMW IR4426STR is power switch driver. It has a matching rise and fall time when charging and discharging the gate of the power switch.

UMW IR4426STR has high latch resistance under all conditions in its rated power and voltage range. When noise spikes of up to 5V (either polarity) occur on the ground pin, the UMW IR4426STR is not damaged. UMW IR4426STR can accept reverse currents up to 500 mA to force back its output without damage or logic confusion. All ports are fully protected by up to 2.0 kV electrostatic discharge (ESD).

3. Applications

- Switch-Mode Power Supplies
- line drivers
- Pulse transformer driver
- Driving MOSFETs and IGBTs
- Motor drives

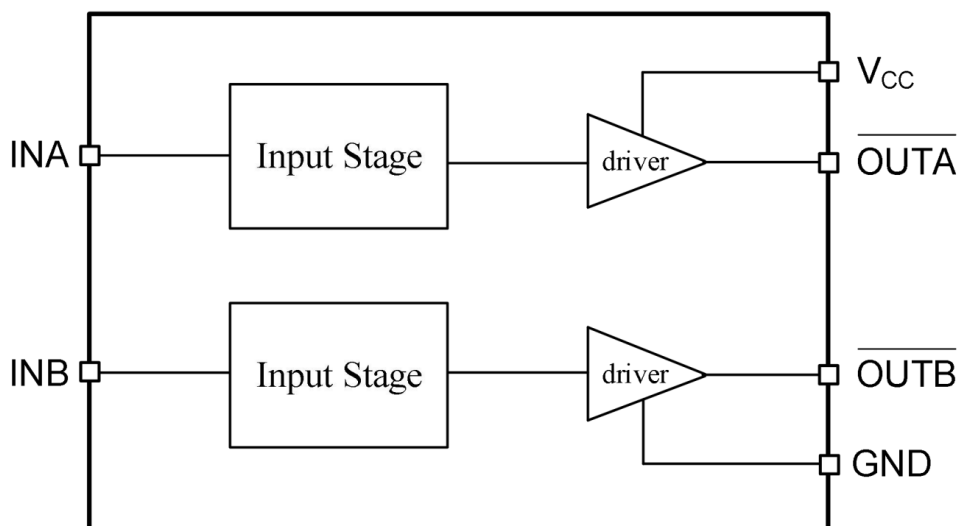
2. Features

- Latch Protection: withstand 0.5 A reverse current
- Ability to Handle Negative Voltages (-10 V) at Inputs
- Low Output Impedance
- Two Independent Gate-Drive Channel
- 2-A Peak Output Current
- 4.5 to 20-V Single-Supply Range
- High Ability of driving capacitive load
- Operating Temperature Range of -40 to 125°C
- Turn on/Turn off Delays: 25ns

- pulse generator
- Switch-Mode Power Supplies
- DC-to-DC Converters
- Class D switching amplifier

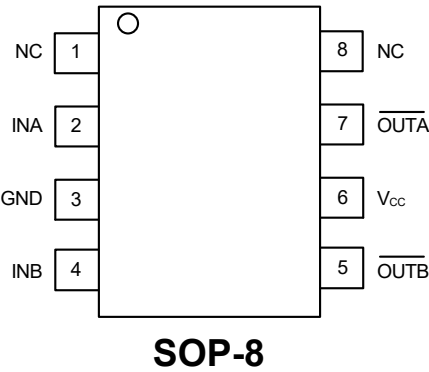


4.Pin Configuration





5.Pinning Information



Lead Definitions

Number	Symbol	Description
1	NC	No connection
2	INA	Input to Channel A
3	GND	Ground: All signals are referenced to this pin
4	INB	Input to Channel B
5	OUTB	Output of Channel B
6	V _{cc}	Bias supply input
7	OUTA	Output of Channel A
8	NC	No connection



6. Absolute Maximum Ratings

Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. All voltages are with respect to GND unless otherwise noted, Currents are positive into, negative out of the specified terminal, environment temperature is 25°C.

Parameter	Symbol	Min	Max	Units
Supply voltage range	V_{CC}		25	V
INA, INB voltage	V_{IN}	-12	25	V
Human body model (HBM)	ESD		2000	V
Charged device model (CDM)			500	V
DFN package power ($T_A \leq 70^\circ\text{C}$)	P_{D1}		340	mW
SOIC package power ($T_A \leq 70^\circ\text{C}$)	P_{D2}		470	mW
Operating junction temperature	T_J		+150	°C
Storage temperature	T_S	-45	+150	°C
Supply voltage range	V_{CC}	4.5	20	V
ambient temperature	T_C	-40	125	°C



7. Electrical Characteristics

$T_A=25^{\circ}\text{C}$, $V_{CC}=15\text{V}$, $C_{LOAD}=1000\text{pF}$ (unless otherwise noted)

Parameter	Symbol	Min	Typ	Max	Units
Input signal high threshold	V_{IH}	2.4			V
Input signal low threshold	V_{IL}			0.8	V
Input current ($V_{IN}=5\text{V}$)	I_{IN+}		5	15	μA
Input current ($V_{IN}=0\text{V}$)	I_{IN-}		-10	-30	μA
High output voltage	V_{OH}	$V_{CC}-0.025$			V
Low output voltage	V_{OL}			0.025	V
Output pullup resistance ($I_O=100\text{mA}$)	R_{OH}		4	8	Ω
Output pulldown resistance ($I_O=100\text{mA}$)	R_{OL}		2	4	Ω
Peak output source current	I_{PK}		2		A
Reverse current that latch protection can withstand (Working cycle $\leq 2\%$, $t \leq 300\mu\text{s}$)	I_{REV}		>0.5		A
Rise time	t_R			30	ns
Fall time	t_F			30	ns
Turn-on propagation delay	t_{ON}		25	50	ns
Turn-off propagation delay	t_{OFF}		25	50	ns
V_{CC} quiescent supply current ($V_{INA}=V_{INB}=\text{HIGH}$)	I_{Q1}			1	mA
V_{CC} quiescent supply current ($V_{INA}=V_{INB}=\text{LOW}$)	I_{Q0}			1	mA



8.Detailed Description

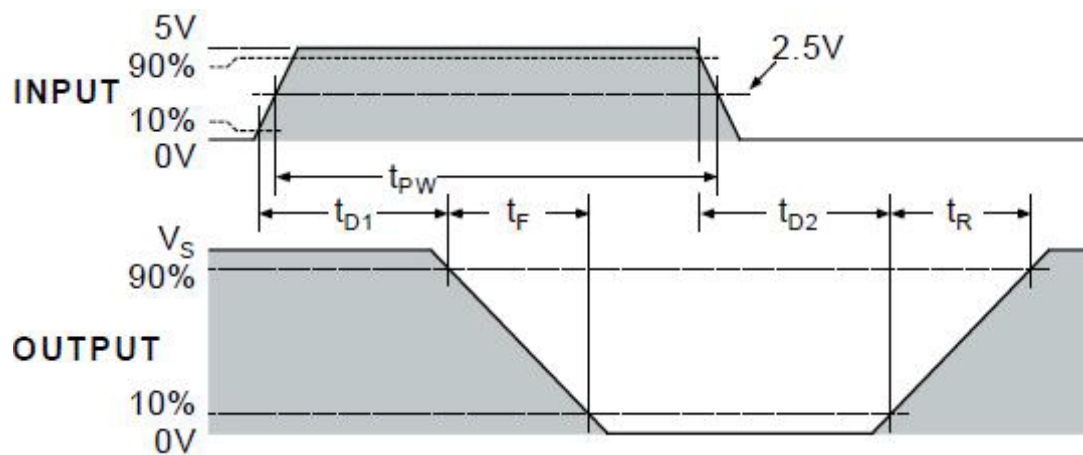


Figure 1. Input-Output Functionality Diagram



9.Functional Block Diagram

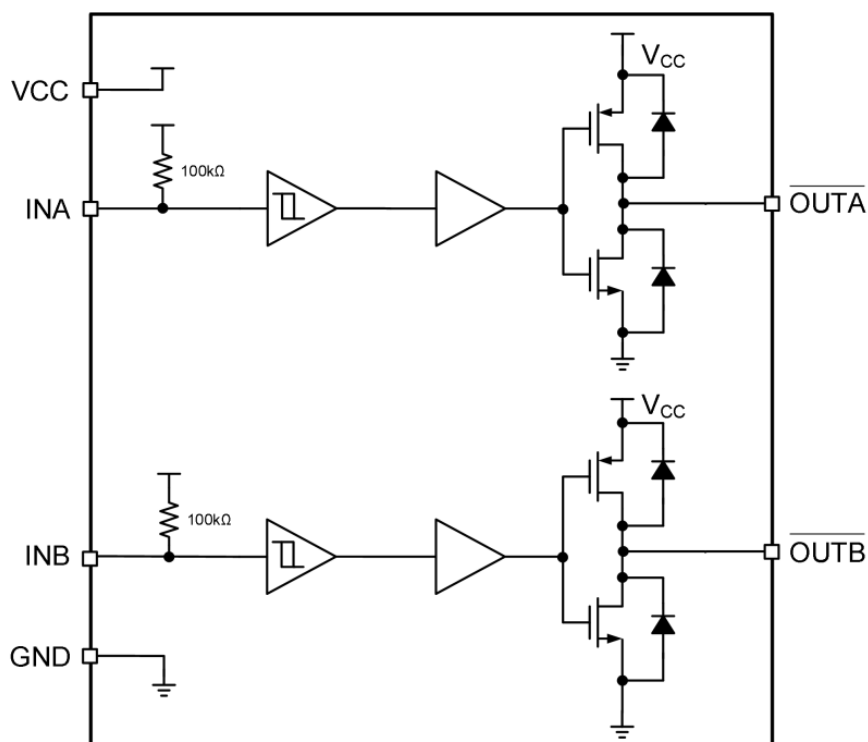


Figure 2. Function Block Diagram of IR4426



10. Typical Application

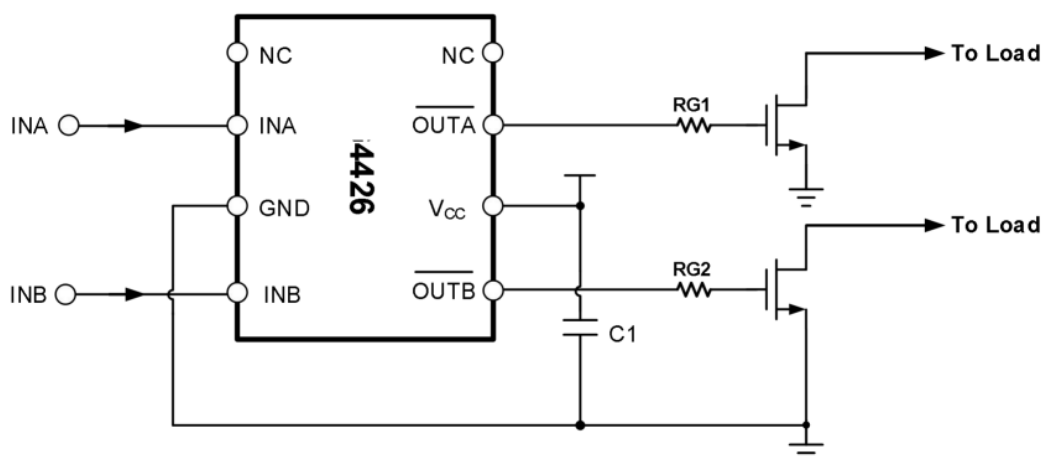
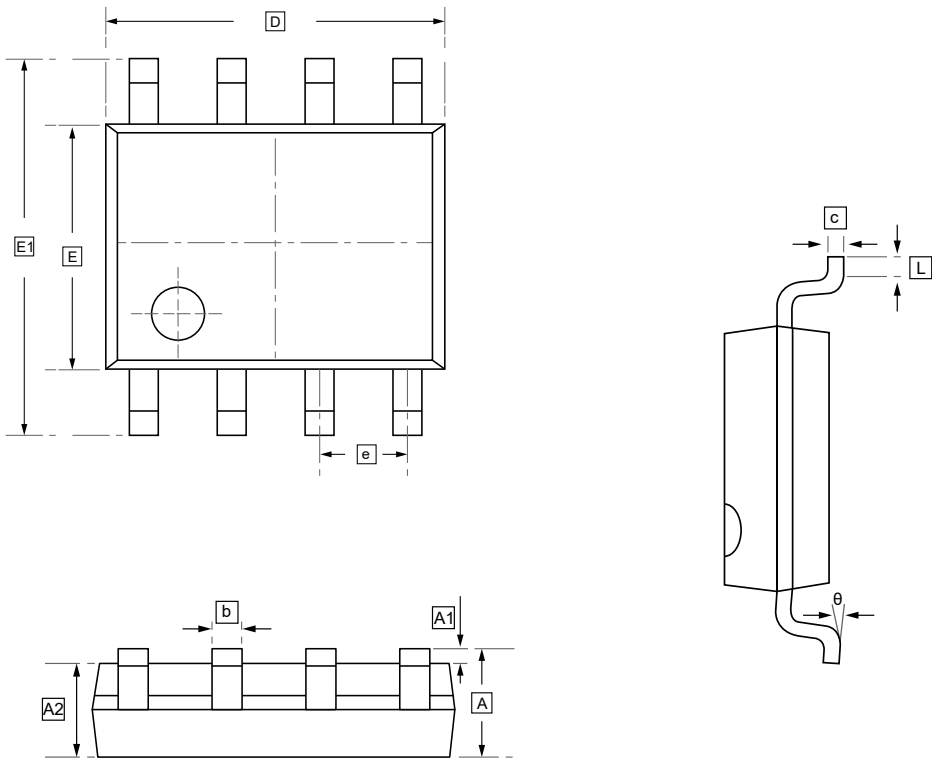


Figure 3. Typical Application Diagram of IR4426



11.SOP-8 Package Outline Dimensions

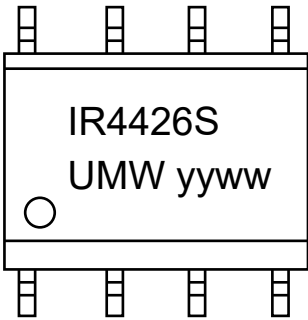


DIMENSIONS (mm are the original dimensions)

Symbol	A	A1	A2	b	c	D	E	E1	e	L	θ
Min	1.350	0.000	1.350	0.330	0.170	4.700	3.800	5.800	1.270	0.400	0°
Max	1.750	0.100	1.550	0.510	0.250	5.100	4.000	6.200	BSC	1.270	8°



12.Ordering information



yy: Year Code
ww: Week Code

Order Code	Package	Base QTY	Delivery Mode
UMW IR4426STR	SOP-8	2500	Tape and reel



13.Disclaimer

UMW reserves the right to make changes to all products, specifications. Customers should obtain the latest version of product documentation and verify the completeness and currency of the information before placing an order.

When applying our products, please do not exceed the maximum rated values, as this may affect the reliability of the entire system. Under certain conditions, any semiconductor product may experience faults or failures. Buyers are responsible for adhering to safety standards and implementing safety measures during system design, prototyping, and manufacturing when using our products to prevent potential failure risks that could lead to personal injury or property damage.

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